Etron 鈺創科技
Etron Technology, Inc.

Embedded Multi-Media Card (e.MMC)

Flash Storage Specification e.MMC 5.1 HS400

EM74I08HVAGC-H

Advance
Revision 1.01
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1.00	April 23, 2025	Initial release
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Etron Technology, Inc. reserves the right to change products or specification without notice.

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1 Introduction

The e.MMC products follow the JEDEC e.MMC 5.1 standards. It is an ideal universal storage solution for many electronic devices, including smart phones, tablets, PDAs, eBook readers, digital cameras, recorders, MP3, MP4 players, electronic learning products, digital TVs and set-top boxes. e.MMC encloses the MLC NAND and e.MMC controller inside as one JEDEC standard package, providing a standard interface to the host. The e.MMC controller directly manages NAND flash, including ECC, wear-leveling, IOPS optimization and read sensing.

1.1 Product Features

- **Packaged NAND flash memory with e.MMC 5.1 interface**
- **Backward compatible with all prior e.MMC specification revisions**
- **Operating Voltage Support:**
  - V_{CC}: (3.3V) 2.7V ~ 3.6V
  - V_{CCQ}: (1.8V) 1.7V ~ 1.95V / (3.3V) 2.7V ~ 3.6V
- **Temperature:**
  - Operating Temperature: TA = -25°C to +85°C
  - Storage without operation: -40°C to +85°C
- **Compliant with e.MMC 5.1 JEDEC Standard Number JESD84-B51**
- **Embedded Multi-Media storage in a single Multi-Chip package.**
- **Package: 153-ball 11.5 x 13.0 x 1.0mm FBGA package**

Table 1-1. Product Information

Part Number	NAND Density	V_{CC}	V_{CCQ}	Package
EM74I08HVAGC-H	8 GB	3.3V	1.8V/3.3V	FBGA

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1.2 e.MMC Specific Feature

- **Bus modes:**
  - High-speed e.MMC protocol
  - Clock frequency : 0-200MHz
  - Ten-wire bus (clock, 1 bit command, 8 bit data bus) and a hardware reset
- **Supports three different data bus widths : 1 bit(default), 4 bits, 8 bits**
  - Data transfer rate: up to 52Mbyte/s (using 8 parallel data lines at 52 MHz)
  - Single data rate : up to 200Mbyte/s @ 200MHz
  - Dual data rate : up to 400Mbyte/s @ 200MHz
- **Error free memory access**
  - Internal error correction code (ECC) to protect data communication
  - Internal enhanced data management algorithm
  - Solid protection of sudden power failure safe-update operations for data content
- **Security**
  - Support secure bad block erase commands
  - Enhanced write Protection with permanent and partial protection options
- **Quality**
  - TSCA, RoHS and HF compliant
- **Field firmware update (FFU)**
- **Enhanced Device Life time**
- **Support Pre EOL information**
- **Optimal Size**
- **Supports Production State Awareness**
- **Supports Power Off Notification for Sleep**
- **Supports HS400**

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2 Ball Assignment

2.1 Package Configuration

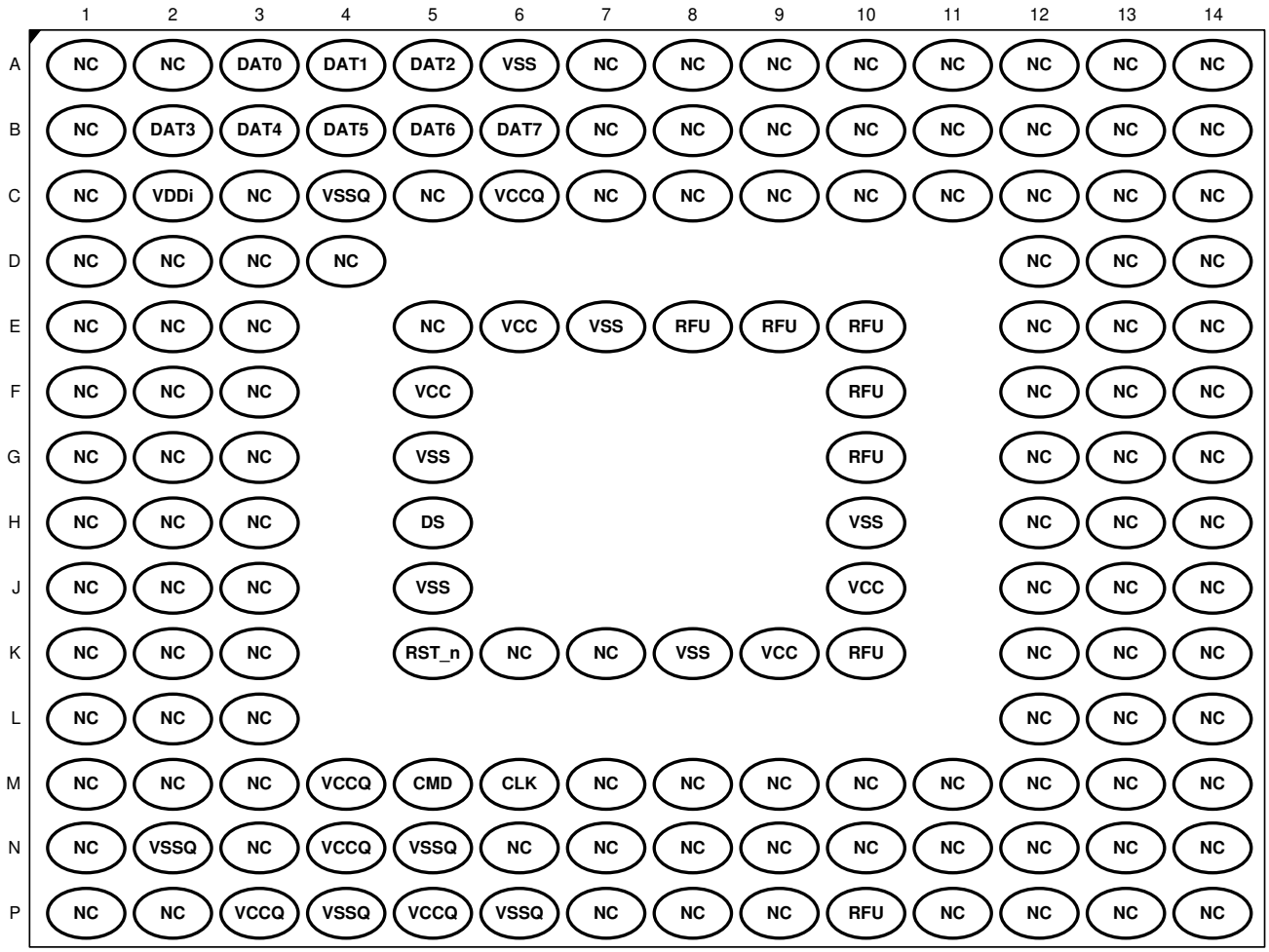


Figure 2-1. 153-FBGA Ball Assignment (Top View)

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3 Specification

3.1 System Performance

The following table provides sequential read and write speeds for all capacities. Performance numbers may vary under different operating conditions.

Table 3-1. Sequential Read / Write Performance

Product	Dynamic booster value (MB/s)	
	Read Sequential	Write Sequential
EM74I08HVAGC-H	280	105

Note 1: Performance numbers might be subject to changes without notice.

3.2 Power Consumption

The device current consumption for various device configurations is defined in the power level field of the EXT_CSD register. The table below summarizes the power consumption values.

Table 3-2. Device Power Consumption

Product	Read(mA)		Write(mA)		Standby(mA)	
	VCCQ(1.8V)	VCC(3.3V)	VCCQ(1.8V)	VCC(3.3V)	VCCQ(1.8V)	VCC(3.3V)
EM74I08HVAGC-H	165	80	90	50	0.07	0.07

Note 1: Values given for an 8-bit bus width, a clock frequency of 200MHz DDR mode, VCC= 3.3V±5%, VCCQ=1.8V±5%

Note 2: Standby current is measured at VCC=3.3V±5%, 8-bit bus width without clock frequency.

Note 3: Current numbers might be subject to changes without notice.

Note 4: The measurement for max RMS current is done as average RMS current consumption over a period of 100ms.

3.3 Partition Capacity

Table 3-3. Partition Capacity

User density	Boot partition 1	Boot partition 2	RPMB
7,837,581,312 Bytes	4096 KB	4096 KB	4096 KB

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4 e.MMC Device and System

4.1 e.MMC System Overview

The e.MMC specification the existence of a host controller and a memory storage array are implied but the operation of these pieces is not fully specified.

The NAND Device consists of a single chip MMC controller and NAND flash memory module. The microcontroller interfaces with a host system allowing data to be written to and read from the NAND flash memory module. The controller allows the host to be independent from details of erasing and programming the flash memory.

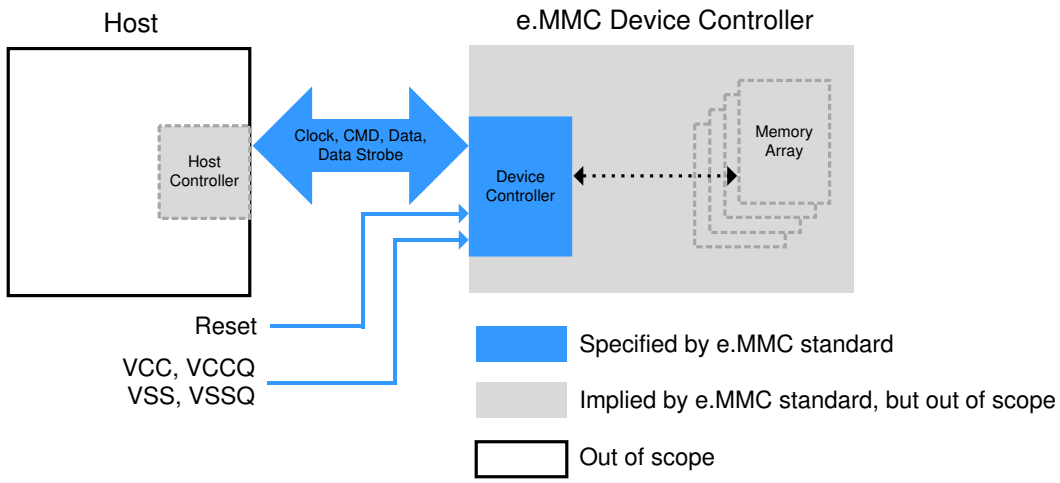


Figure 4-1. e.MMC System Overview

4.2 Memory Addressing

Previous implementations of the e.MMC specification are following byte addressing with 32 bit field. This addressing mechanism permitted for e.MMC densities up to and including 2 GB.

To support larger densities, the addressing mechanism was update to support sector addresses (512 B sectors). The sector addresses shall be used for all devices with capacity larger than 2 GB.

To determine the addressing mode, use the host should read bit [30:29] in the OCR register.

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4.3 e.MMC Device Overview

The e.MMC device transfers data via a configurable number of data bus signals. The communication signals are:

Table 4-1. Communication Interface

Name	Type	Description
CLK	I	**Clock:** Each cycle of this signal directs a one bit transfer on the command and either a one bit (1x) or a two bits transfer (2x) on all the data lines. The frequency may vary between zero and the maximum clock frequency.
DAT[7:0]	I/O/PP	**Data:** These are bidirectional data channels. The DAT signals operate in push-pull mode. Only the Device or the host is driving these signals at a time. By default, after power up or reset, only DAT0 is used for data transfer. A wider data bus can be configured for data transfer, using either DAT0-DAT3 or DAT0- DAT7, by the e.MMC host controller. The e.MMC device includes internal pull-ups for data lines DAT1-DAT7. Immediately after entering the 4-bit mode, the device disconnects the internal pull ups of lines DAT1, DAT2, and DAT3. Correspondingly, immediately after entering to the 8-bit mode, the device disconnects the internal pull-ups of lines DAT1-DAT7.
CMD	I/O/PP/OD	**Command:** This signal is a bidirectional command channel used for device initialization and transfer of commands. The CMD signal has two operation modes: open-drain for initialization mode, and push-pull for fast command transfer. Commands are sent from the e.MMC host controller to the e.MMC device and responses are sent from the device to the host.
RST_n	I	**Hardware Reset:** By default, hardware reset is disabled and must be enabled in the EXT_CSD register if used. Otherwise, it can be left un-connected.
VCC	S	Supply voltage for core
VCCQ	S	Supply voltage for I/O
VSS	S	Supply ground for core
VSSQ	S	Supply ground for I/O
DS	O/PP	**Data Strobe:** This signal is generated by the device and used for output in HS400 mode. The frequency of this signal follows the frequency of CLK. For data output each cycle of this signal directs two bits transfer(2x) on the data - one bit for positive edge and the other bit for negative edge. For CRC status response output and CMD response output (enabled only HS400 enhanced strobe mode), the CRC status is latched on the positive edge only, and don't care on the negative edge.
RFU	-	Reserved for future use: These pins are not internally connected. Leave floating
NC	-	Not Connected: These pins are not internally connected. Signals can be routed through these balls to ease printed circuit board design.
VDDi	-	Internal Voltage Node: Note that this is not a power supply input. This pin provides access to the output of an internal voltage regulator to allow for the connection of an external Creg capacitor.
Note: I=Input; O=Output; P=Push-Pull; OD=Open Drain; NC=Not Connected(or logical high); S=Power Supply		

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Table 4-2. e.MMC Register

Name	Width (Bytes)	Description	Implementation
CID	16	Device Identification number, an individual number for identification.	Mandatory
RCA	2	Relative Device Address is the Device system address, dynamically assigned by the host during initialization.	Mandatory
DSR	2	Driver Stage Register, to configure the Device's output drivers.	Optional
CSD	16	Device Specific Data, information about the Device operation conditions.	Mandatory
OCR	4	Operation Conditions Register. Used by a special broadcast command to identify the voltage type of the Device.	Mandatory
EXT_CSD	512	Extended Device Specific Data. Contains information about the Device capabilities and selected modes. Introduced in standard v4.0	Mandatory

The host may reset the device by:

- Switching the power supply off and back on. The device shall have its own power-on detection circuitry which puts the device into a defined state after the power-on Device.
- A reset signal
- By sending a special command

4.4 Bus Protocol

After a power-on reset, the host must initialize the device by a special message-based e.MMC bus protocol. For more details, refer to the JEDEC Standard Specification JESD84-B51.

4.5 Bus Speed Modes

The e.MMC standard specifies several bus speed modes, which are detailed in the following table.

Table 4-3. e.MMC Bus Mode

Mode	Data Rate	IO Voltage	Bus Width	CLK Frequency	Max Data Transfer (implies x8 bus width)
Backwards Compatibility with legacy MMC card	Single	3.3V / 1.8V	1, 4, 8	0 – 26 MHz	26 MB/s
High Speed SDR	Single	3.3V / 1.8V	4, 8	0 – 52 MHz	52 MB/s
High Speed DDR	Dual	3.3V / 1.8V	4, 8	0 – 52 MHz	104 MB/s
HS200	Single	1.8V	4, 8	0 – 200 MHz	200 MB/s
HS400	Dual	1.8V	8	0 – 200 MHz	400 MB/s

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4.5.1 HS400 Bus Speed mode

The HS400 mode has the following features

- DDR Data sampling method
- CLK frequency up to 200MHz, Data rate is – up to 400MB/s
- Only 8-bit bus width supported
- Signaling levels of 1.8V
- Support up to 5 selective Drive Strength

Data strobe signal is toggled only for Data out and CRC response.

4.5.2 HS400 System Block Diagram

The diagram below shows a typical HS400 Host and Device system. The host has a clock generator, which supplies CLK to the Device. For read operations, Data Strobe is generated by device output circuit. Host receives the data which is aligned to the edge of Data Strobe.

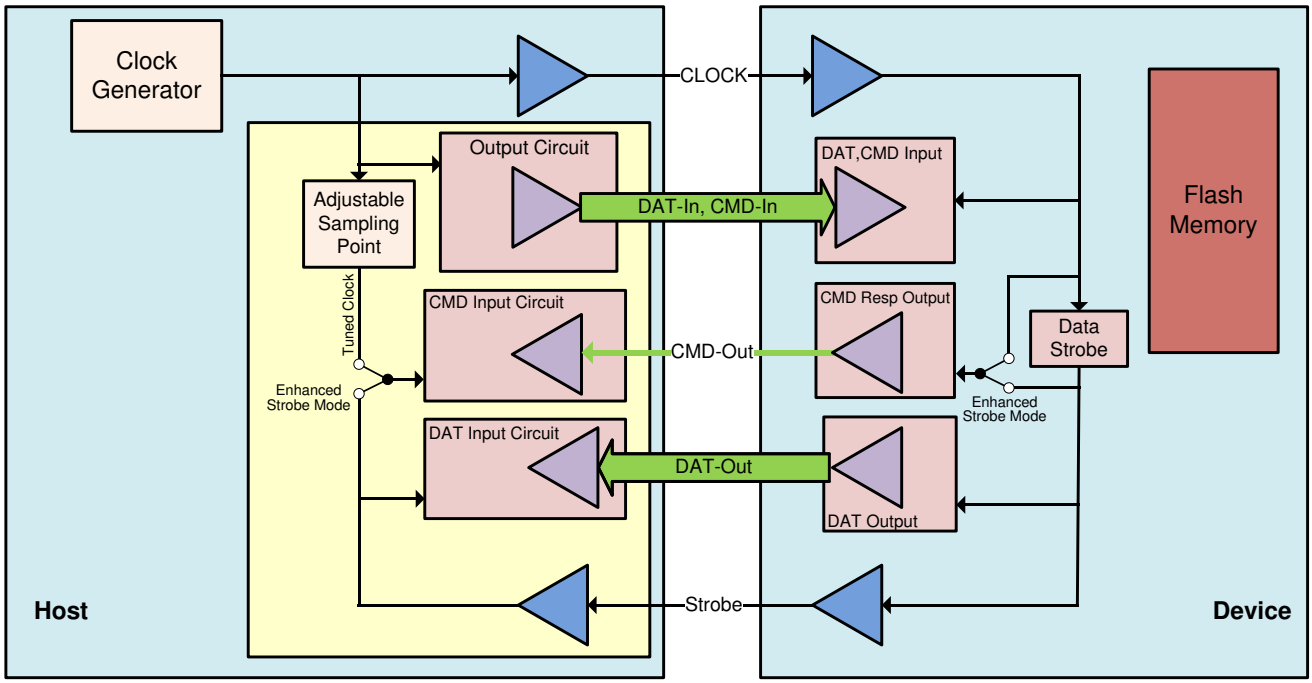


Figure 4-2. HS400 Host and Device block diagram

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5 e.MMC Functional Description

5.1 e.MMC Overview

All communication between host and device are controlled by the host (main chip). The host sends a command, which results in a device response. For more details, refer to the JEDEC Standard Specification JESD84-B51.

Five operation modes are defined for the e.MMC system:

- Boot operation mode
- Device identification mode
- Interrupt mode
- Data transfer mode
- Inactive mode

5.2 Boot Operation Mode

In boot operation mode, the master (e.MMC host) can read boot data from the slave (e.MMC device) by keeping CMD line low or sending CMD0 with argument + 0xFFFFFFFA, before issuing CMD1. The data can be read from either boot area or user area depending on register setting. For more details, refer to the JEDEC Standard Specification JESD84-B51.

5.3 Device Identification Mode

While in device identification mode the host resets the device, validates operation voltage range and access mode, identifies the device and assigns a Relative Device Address (RCA) to the device on the bus. All data communication in the Device Identification Mode uses the command line (CMD) only. For more details, refer to the JEDEC Standard Specification JESD84-B51.

5.4 Interrupt Mode

The interrupt mode on the e.MMC system enables the master (e.MMC host) to grant the transmission allowance to the slaves (Device) simultaneously. This mode reduces the polling load for the host and hence, the power consumption of the system, while maintaining adequate responsiveness of the host to a Device request for service. Supporting e.MMC interrupt mode is an option, both for the host and the Device. For more details, refer to the JEDEC Standard Specification JESD84-B51.

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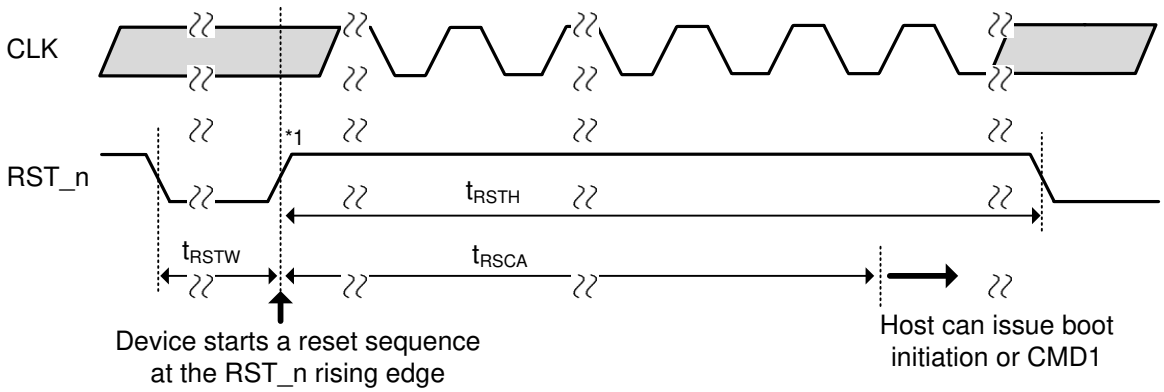
5.5 Data Transfer Mode

When the Device is in Stand-by State, communication over the CMD and DAT lines will be performed in push-pull mode. For more details, refer to the JEDEC Standard Specification JESD84-B51.

5.6 Inactive Mode

The device will enter inactive mode if either the device operating voltage range or access mode is not valid. The device can also enter inactive mode with GO_INACTIVE_STATE command (CMD15). The device will reset to Pre-idle state with power cycle. For more details, refer to the JEDEC Standard Specification JESD84-B51.

5.7 H/W Reset Operation



Note 1. Device will detect the rising edge of RST_n signal to trigger internal reset sequence.

Figure 5-1. H/W Reset Waveform

Table 5-1. H/W Reset Timing Parameters

Symbol	Comment	Min.	Max.	Unit
tRSTW	RST_n pulse width	1	-	us
tRSCA	RST_n to Command time	200(1)	-	us
tRSTH	RST_n high period (interval time)	1	-	us

Note1: 74 cycles of clock signal required before issuing CMD1 or CMD0 with argument 0xFFFFFFFA

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5.8 Noise Filtering Timing for H/W Reset

Device must filter out 5ns or less pulse width for noise immunity.

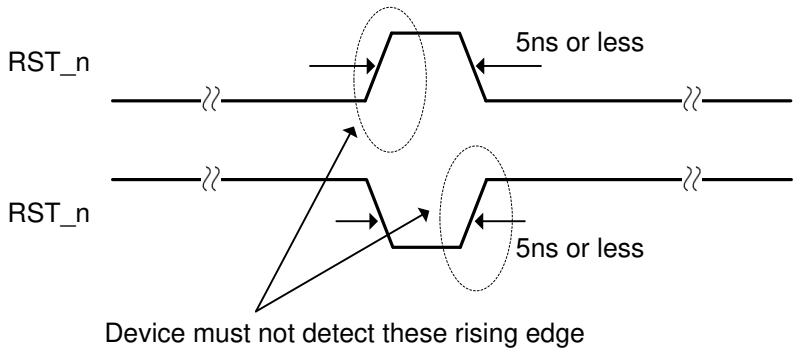


Figure 5-2. Noise Filtering Timing for H/W Reset

Device must not detect these rising edge.
Device must not detect 5ns or less of positive or negative RST_n pulse.
Device must detect more than or equal to 1us of positive or negative RST_n pulse width.

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6 Register Settings

Within the Device interface six registers are defined: OCR, CID, CSD, EXT_CSD, RCA and DSR. These can be accessed only by corresponding commands. For more details, refer to the JEDEC Standard Specification JESD84-B51.

6.1 OCR Register

The 32-bit operation conditions register (OCR) stores the VDD voltage profile of the device and the access mode indication. In addition, this register includes a status information bit. This status bit is set if the device power up procedure has been finished. The OCR register shall be implemented by all devices.

Table 6-1. OCR Register Setting

OCR Register Definitions OCR bit	VDD voltage window	High Voltage Multi-Media Card	Dual voltage Multi-Media Card and e.MMC
[6:0]	Reserved	00 00000b	00 00000b
[7]	1.70 - 1.95V	0b	1b
[14:8]	2.0 - 2.6V	000 0000b	000 0000b
[23:15]	2.7 - 3.6V	1 1111 1111b	1 1111 1111b
[28:24]	Reserved	0 0000b	0 0000b
[30:29]	Access Mode	00b (byte mode) 10b (sector mode)	00b (byte mode) 10b (sector mode)
[31]	(Device power up status bit (busy)[1]		
Note1：This bit is set to LOW if the Device has not finished the power up routine.			

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6.2 Card Identification Register (CID)

The Card Identification (CID) register is 128 bits wide. It contains the Device identification information used during the device identification phase (e.MMC protocol). For more details, refer to the JEDEC Standard Specification JESD84-B51.

Table 6-2. CID Register Setting

CID Fields Name	Field	Width	CID slice	Value
Manufacturer ID	MID	8	[127:120]	D5h
Reserved	-	6	[119:114]	0h
Device/BGA	CBX	2	[113:112]	1h
OEM/Application ID	OID	8	[111:104]	01h
Product name	PNM	48	[103:56]	(534337344948h) SC74IH
Product revision	PRV	8	[55:48]	51h*
Product serial number	PSN	32	[47:16]	Random by Production
Manufacturing date	MDT	8	[15:8]	month, year
CRC7 checksum	CRC	7	[7:1]	3C (Note 1)
not used, always “1”	-	1	[0]	1h

Note1. The descriptions are same as e.MMC JEDEC standard.

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6.3 Card Specific Data Register [CSD]

The Card-Specific Data (CSD) register provides information on how to access the contents stored in e.MMC. The CSD registers are used to define the error correction type, maximum data access time, data transfer speed, data format…etc. For more details, refer to the JEDEC Standard Specification JESD84-B51.

Table 6-3. CSD Register Setting

Name	Field	Width	CSD-slice	Value
CSD structure	CSD_STRUCTURE	2	[127:126]	3h
System specification version	SPEC_VERS	4	[125:122]	4h
Reserved	-	2	[121:120]	0h
Data read access-time 1	TAAC	8	[119:112]	4Fh
Data read access-time 2 in CLK cycles (NSAC*100)	NSAC	8	[111:104]	1h
Max. bus clock frequency	TRAN_SPEED	8	[103:96]	32h
Device command classes	CCC	12	[95:84]	8F5h
Max. read data block length	READ_BL_LEN	4	[83:80]	9h
Partial blocks for read allowed	READ_BL_PARTIAL	1	[79:79]	0h
Write block misalignment	WRITE_BLK_MISALIGN	1	[78:78]	0h
Read block misalignment	READ_BLK_MISALIGN	1	[77:77]	0h
DSR implemented	DSR_IMP	1	[76:76]	0h
Reserved	-	2	[75:74]	0h
Device size	C_SIZE	12	[73:62]	FFFh
Max. read current @ VDD min	VDD_R_CURR_MIN	3	[61:59]	7h
Max. read current @ VDD max	VDD_R_CURR_MAX	3	[58:56]	7h
Max. write current @ VDD min	VDD_W_CURR_MIN	3	[55:53]	7h
Max. write current @ VDD max	VDD_W_CURR_MAX	3	[52:50]	7h
Device size multiplier	C_SIZE_MULT	3	[49:47]	7h
Erase group size	ERASE_GRP_SIZE	5	[46:42]	0Fh
Erase group size multiplier	ERASE_GRP_MULT	5	[41:37]	1Fh
Write protect group size	WP_GRP_SIZE	5	[36:32]	0Fh
Write protect group enable	WP_GRP_ENABLE	1	[31:31]	1h
Manufacturer default ECC	DEFAULT_ECC	2	[30:29]	0h
Write speed factor	R2W_FACTOR	3	[28:26]	2h
Max. write data block length	WRITE_BL_LEN	4	[25:22]	9
Partial blocks for write allowed	WRITE_BL_PARTIAL	1	[21:21]	0h
Reserved	-	4	[20:17]	0h
Content protection application	CONTENT_PROT_APP	1	[16:16]	0h
File format group	FILE_FORMAT_GRP	1	[15:15]	0h
Copy flag (OTP)	COPY	1	[14:14]	0h
Permanent write protection	PERM_WRITE_PROTECT	1	[13:13]	0h
Temporary write protection	TMP_WRITE_PROTECT	1	[12:12]	0h
File format	FILE_FORMAT	2	[11:10]	0h
ECC code	ECC	2	[9:8]	0h
CRC	CRC	7	[7:1]	64h
Not used, always'1'	-	1	[0:0]	1h

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6.4 Extended Card Specific Data Register [EXT_CSD]

The Extended CSD register defines the Device properties and selected modes. It is 512 bytes long. The most significant 320 bytes are the Properties segment, which defines the Device capabilities and cannot be modified by the host. The lower 192 bytes are the Modes segment, which defines the configuration the Device is working in. These modes can be changed by the host by means of the SWITCH command. For more details, refer to the JEDEC Standard Specification JESD84-B51.

Table 6-4. Extended CSD Register Setting

Name	Field	Size (Bytes)	CSD-slice	Value
Properties Segment				
Reserved (note1)	–	6	[511:506]	0h
Extended Security Commands Error	EXT_SECURITY_ERR	1	[505]	0h
Supported Command Sets	S_CMD_SET	1	[504]	1h
HPI features	HPI_FEATURES	1	[503]	1h
Background operations support	BKOPS_SUPPORT	1	[502]	1h
Max packed read commands	MAX_PACKED_READS	1	[501]	3Ch
Max packed write commands	MAX_PACKED_WRITES	1	[500]	20h
Data Tag Support	DATA_TAG_SUPPORT	1	[499]	1h
Tag Unit Size	TAG_UNIT_SIZE	1	[498]	3h
Tag Resources Size	TAG_RES_SIZE	1	[497]	0h
Context management capabilities	CONTEXT_CAPABILITIES	1	[496]	5h
Large Unit size	LARGE_UNIT_SIZE_M1	1	[495]	17h
Extended partitions attribute support	EXT_SUPPORT	1	[494]	3h
Supported modes	SUPPORTED_MODES	1	[493]	01h
FFU features	FFU_FEATURES	1	[492]	0h
Operation codes timeout	OPERATION_CODE_TIME_OUT	1	[491]	0h
FFU Argument	FFU_ARG	4	[490:487]	65535
Barrier support	BARRIER_SUPPORT	1	[486:486]	1h
Reserved	Reserved	177	[485:309]	-
CMD Queuing Support	CMQ_SUPPORT	1	[308:308]	1h
CMD Queuing Depth	CMQ_DEPTH	1	[307:307]	1Fh
Reserved	Reserved	1	[306:306]	-
Number of FW sectors correctly programmed	NUMBER_OF_FW_SECTORS_ CORRECTLY_PROGRAMMED	4	[305:302]	0h
Vendor proprietary health report	VENDOR_PROPRIETARY_ HEALTH_REPORT	32	[301:270]	0h
Device life time estimation type B	DEVICE_LIFE_TIME_EST_TYP_B	1	[269]	01h
Device life time estimation type A	DEVICE_LIFE_TIME_EST_TYP_A	1	[268]	01h
Pre EOL information	PRE_EOL_INFO	1	[267]	01h
Optimal read size	OPTIMAL_READ_SIZE	1	[266]	01h
Optimal write size	OPTIMAL_WRITE_SIZE	1	[265]	08h
Optimal trim unit size	OPTIMAL_TRIM_UNIT_SIZE	1	[264]	01h
Device version	DEVICE_VERSION	2	[263:262]	0h
Firmware version	FIRMWARE_VERSION	8	[261:254]	(note5) *
Power class for 200MHz, DDR at VCC=3.6V	PWR_CL_DDR_200_360	1	[253]	0h
Cache size	CACHE_SIZE	4	[252:249]	512
Generic CMD6 timeout	GENERIC_CMD6_TIME	1	[248]	32h

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Power off notification(long) time out	POWER_OFF_LONG_TIME	1	[247]	FFh
Background operations status	BKOPS_STATUS	1	[246]	0h
Number of correctly programmed sectors	CORRECTLY_PRG_SECTORS_NUM	4	[245:242]	0h
1st initialization time after partitioning	INI_TIMEOUT_AP	1	[241]	64h
Cache Flushing Policy	CACHE_FLUSH_POLICY	1	[240]	1h
Power class for 52MHz, DDR at 3.6V	PWR_CL_DDR_52_360	1	[239]	0h
Power class for 52MHz, DDR at 1.95V	PWR_CL_DDR_52_195	1	[238]	0h
Power class for 200MHz at 3.6V	PWR_CL_200_360	1	[237]	0h
Power class for 200MHz, at 1.95V	PWR_CL_200_195	1	[236]	0h
Minimum Write Performance for 8bit at 52MHz in DDR mode	MIN_PERF_DDR_W_8_52	1	[235]	0h
Minimum Read Performance for 8bit at 52MHz in DDR mode	MIN_PERF_DDR_R_8_52	1	[234]	0h
Reserved (note1)	–	1	[233]	0h
TRIM Multiplier	TRIM_MULT	1	[232]	5h
Secure Feature support	SEC_FEATURE_SUPPORT	1	[231]	55h
Secure Erase Multiplier	SEC_ERASE_MULT	1	[230]	F7h
Secure TRIM Multiplier	SEC_TRIM_MULT	1	[229]	F7h
Boot information	BOOT_INFO	1	[228]	7h
Reserved (note1)	–	1	[227]	0h
Boot partition size	BOOT_SIZE_MULTI	1	[226]	20h*
Access size	ACC_SIZE	1	[225]	7h
High-capacity erase unit size	HC_ERASE_GRP_SIZE	1	[224]	1h
High-capacity erase timeout	ERASE_TIMEOUT_MULT	1	[223]	11h
Reliable write sector count	REL_WR_SEC_C	1	[222]	1h
High-capacity write protect group size	HC_WP_GRP_SIZE	1	[221]	10h
Sleep current (VCC)	S_C_VCC	1	[220]	8h
Sleep current (VCCQ)	S_C_VCCQ	1	[219]	8h
Production state awareness Timeout	PRODUCTION_STATE_AWARENESS_TIMEOUT	1	[218]	14h
Sleep/awake timeout	S_A_TIMEOUT	1	[217]	15h
Sleep Notification time out	SLEEP_NOTIFICATION_TIME	1	[216]	0Fh
Sector Count	SEC_COUNT	4	[215:212]	15307776
Reserved (note1)	–	1	[211]	1h
Minimum Write Performance for 8bit at 52MHz	MIN_PERF_W_8_52	1	[210]	8h
Minimum Read Performance for 8bit at 52MHz	MIN_PERF_R_8_52	1	[209]	8h
Minimum Write Performance for 8bit at 26MHz, for 4bit at 52MHz	MIN_PERF_W_8_26_4_52	1	[208]	8h
Minimum Read Performance for 8bit at 26MHz, for 4bit at 52MHz	MIN_PERF_R_8_26_4_52	1	[207]	8h
Minimum Write Performance for 4bit at 26MHz	MIN_PERF_W_4_26	1	[206]	8h
Minimum Read Performance for 4bit at 26MHz	MIN_PERF_R_4_26	1	[205]	8h
Reserved (note1)	–	1	[204]	0h
Power class for 26MHz at 3.6V 1 R	PWR_CL_26_360	1	[203]	0h
Power class for 52MHz at 3.6V 1 R	PWR_CL_52_360	1	[202]	0h
Power class for 26MHz at 1.95V 1 R	PWR_CL_26_195	1	[201]	0h
Power class for 52MHz at 1.95V 1 R	PWR_CL_52_195	1	[200]	0h
Partition switching timing	PARTITION_SWITCH_TIME	1	[199]	3h
Out-of-interrupt busy timing	OUT_OF_INTERRUPT_TIME	1	[198]	FFh

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I/O Driver Strength	DRIVER_STRENGTH	1	[197]	1Fh
Device type	CARD_TYPE	1	[196]	57h
Reserved (note1)	–	1	[195]	0h
CSD structure version	CSD_STRUCTURE	1	[194]	2h
Reserved (note1)	–	1	[193]	0h
Extended CSD revision	EXT_CSD_REV	1	[192]	08h
Modes Segment				
Command set	CMD_SET	1	[191]	0h
Reserved (note1)	–	1	[190]	0h
Command set revision	CMD_SET_REV	1	[189]	0h
Reserved (note1)	–	1	[188]	0h
Power class	POWER_CLASS	1	[187]	0h
Reserved (note1)	–	1	[186]	0h
High-speed interface timing	HS_TIMING	1	[185]	1h (note 3)
Strobe Support	STROBE_SUPPORT	1	[184]	1h
Bus width mode	BUS_WIDTH	1	[183]	2h (note 4)
Reserved (note1)	–	1	[182]	0h
Erased memory content	ERASED_MEM_CONT	1	[181]	0h
Reserved (note1)	–	1	[180]	0h
Partition configuration	PARTITION_CONFIG	1	[179]	0h
Boot config protection	BOOT_CONFIG_PROT	1	[178]	0h
Boot bus Conditions	BOOT_BUS_CONDITIONS	1	[177]	0h
Reserved (note1)	–	1	[176]	0h
High-density erase group definition	ERASE_GROUP_DEF	1	[175]	0h
Boot write protection status registers	BOOT_WP_STATUS	1	[174]	0h
Boot area write protection register	BOOT_WP	1	[173]	0h
Reserved (note1)	–	1	[172]	0h
User area write protection register	USER_WP	1	[171]	0h
Reserved (note1)	–	1	[170]	1Eh
FW configuration	FW_CONFIG	1	[169]	0h
RPMB Size	RPMB_SIZE_MULT		[168]	20h*
Write reliability setting register	WR_REL_SET		[167]	1Fh
Write reliability parameter register	WR_REL_PARAM	1	[166]	15h
Start Sanitize operation	SANITIZE_START	1	[165]	0h
Manually start background operation	BKOPS_START	1	[164]	0h
Enable background operations handshake	BKOPS_EN	1	[163]	0h
H/W reset function	RST_n_FUNCTION	1	[162]	0h
HPI management	HPI_MGMT	1	[161]	0h
Partitioning Support	PARTITIONING_SUPPORT	1	[160]	7h
Max Enhanced Area Size	MAX_ENH_SIZE_MULT	3	[159:157]	467
Partitions attribute	PARTITIONS_ATTRIBUTE	1	[156]	0h
Partitioning Setting	PARTITION_SETTING_COMPLETED	1	[155]	0h
General Purpose Partition Size	GP_SIZE_MULT 4	3	[154:152]	0h
General Purpose Partition Size	GP_SIZE_MULT3	3	[151:149]	0h
General Purpose Partition Size	GP_SIZE_MULT2	3	[148:146]	0h
General Purpose Partition Size	GP_SIZE_MULT1	3	[145:143]	0h
Enhanced User Data Area Size	ENH_SIZE_MULT	3	[142:140]	0h
Enhanced User Data Start Address	ENH_START_ADDR	4	[139:136]	0h
Reserved (note1)	–	1	[135]	0h
Bad Block Management mode	SEC_BAD_BLK_MGMNT	1	[134]	0h
Reserved (note1)	–	1	[133]	0h
Package Case Temperature is controlled	TCASE_SUPPORT	1	[132]	0h

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Periodic Wake-up	PERIODIC_WAKEUP	1	[131]	0h
Program CID/CSD in DDR mode support	PROGRAM_CID_CSD_DDR_ SUPPORT	1	[130]	1h
Reserved (note1)	–	2	[129:128]	-
Vendor Specific Fields	VENDOR_SPECIFIC_FIELD	64	[127:64]	-
Native sector size	NATIVE_SECTOR_SIZE	1	[63]	0h
Sector size emulation	USE_NATIVE_SECTOR	1	[62]	0h
Sector size	DATA_SECTOR_SIZE	1	[61]	0h
1st initialization after disabling sector size emulation	INI_TIMEOUT_EMU	1	[60]	0h
Class 6 commands control	CLASS_6_CTRL	1	[59]	0h
Number of addressed group to be Released	DYNCAP_NEEDED	1	[58]	0h
Exception events control	EXCEPTION_EVENTS_CTRL	2	[57:56]	0h
Exception events status	EXCEPTION_EVENTS_STATUS	2	[55:54]	0h
Extended Partitions Attribute	EXT_PARTITIONS_ATTRIBUTE	2	[53:52]	0h
Context configuration	CONTEXT_CONF	15	[51:37]	0h
Packed command status	PACKED_COMMAND_STATUS	1	[36]	0h
Packed command failure index	PACKED_FAILURE_INDEX	1	[35]	0h
Power Off Notification	POWER_OFF_NOTIFICATION	1	[34]	0h
Control to turn the Cache ON/OFF	CACHE_CTRL	1	[33]	0h
Flushing of the cache	FLUSH_CACHE	1	[32]	0h
Reserved (note1)	Reserved	1	[31]	0h
Mode config	MODE_CONFIG	1	[30:30]	0h
Mode operation codes	MODE_OPERATION_CODES	1	[29:29]	0h
Reserved (note1)	Reserved	2	[28:27]	-
FFU status	FFU_STATUS	1	[26:26]	0h
Per loading data size	PRE_LOADING_DATA_SIZE	4	[25:22]	0h
Max pre loading data size	MAX_PRE_LOADING_DATA_SIZE	4	[21:18]	7527168
Product state awareness enablement	PRODUCT_STATE_AWARENESS _ENABLEMENT	1	[17:17]	01h
Secure removal type	SECURE_REMOVAL_TYPE	1	[16:16]	01h
Command Queue Mode enable	CMQ_MODE_EN	1	[15:15]	0h
Reserved (note1)	Reserved	15	[14:0]	-

Note 1. Reserved bits should read as “0.”

Note 2. Obsolete values should be don’t care.

Note 3. This field is 0 after power-on, H/W reset or software reset, thus selecting the backwards compatibility interface timing for the Device. If the host sets 1 to this field, the Device changes its timing to high speed interface timing. If the host sets value 2 the Device changes its timing to HS200 interface timing, If the host sets HS_TIMING[3:0] to 0x3,the device changes its timing to HS400 interface timing. Refer to JEDEC Standard Specification No.JESD84-B51 for details.

Note 4. It is set to ‘0’ (1 bit data bus) after power up and can be changed by a SWITCH command.

Note 5. * Changed by Firmware release note.

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6.5 RCA Register

The writable 16-bit relative Device address (RCA) register carries the Device address assigned by the host during the Device identification. This address is used for the addressed host-Device communication after the Device identification procedure. The default value of the RCA register is 0x0001. The value 0x0000 is reserved to set all Devices into the Stand-by State with CMD7.

6.6 DSR Register

The 16-bit driver-level registers (DSR) are defined in the JEDEC standard JESD84-B51. It can be optionally used to improve the bus performance for extended operating conditions (depending on parameters like bus length, transfer rate or number of Devices). The CSD register carries the information about the DSR register usage.

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7 e.MMC bus

The e.MMC bus has ten communication lines and three supply lines:

- CMD: Command is a bidirectional signal. The host and Device drivers are operating in two modes, open drain and push/pull.
- DAT0~7: Data lines are bidirectional signals. Host and Device drivers are operating in push-pull mode.
- CLK: Clock is a host to Device signal. CLK operates in push-pull mode.
- Data Strobe: Data Strobe is a Device to host signal. Data Strobe operates in push-pull mode.

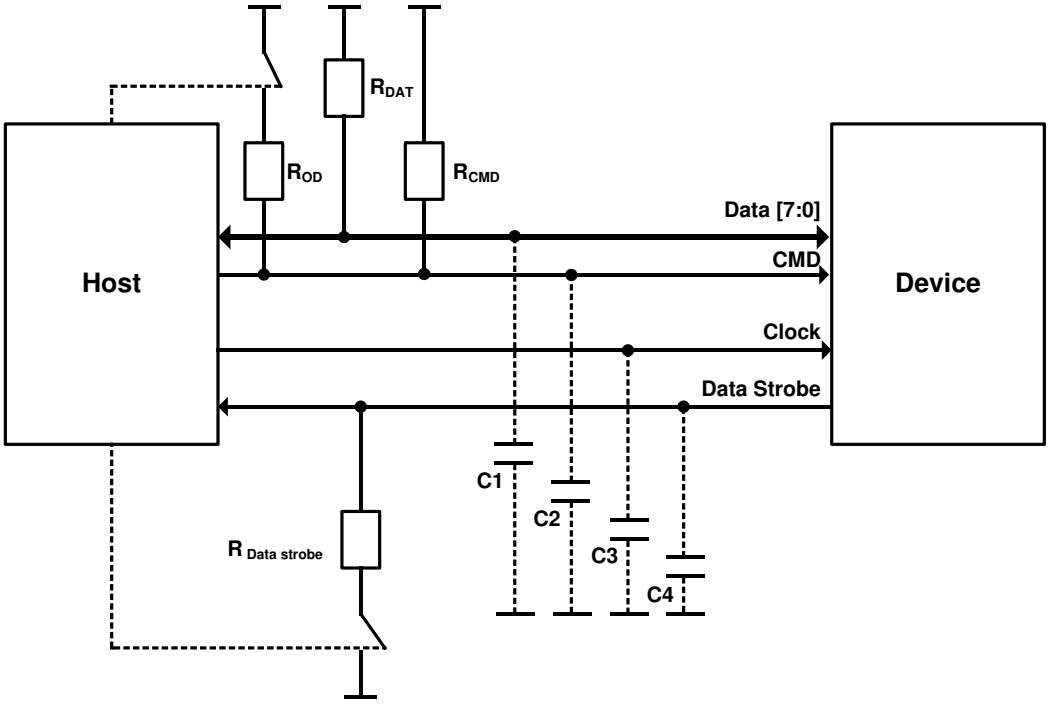


Figure 7-1. Bus Circuitry Diagram

The R_{OD} is switched on and off by the host synchronously to the open-drain and push-pull mode transitions. The host does not have to have open drain drivers, but must recognize this mode to switch on the R_{OD}. R_{DAT} and R_{CMD} are pull-up resistors protecting the CMD and the DAT lines against bus floating device when all device drivers are in a high-impedance mode.

A constant current source can replace the R_{OD} by achieving a better performance (constant slopes for the signal rising and falling edges). If the host does not allow the switchable R_{OD} implementation, a fixed R_{CMD} can be used. Consequently, the maximum operating frequency in the open drain mode has to be reduced if the used R_{CMD} value is higher than the minimal one given in.

$R_{Data\ strobe}$ is pull-down resistor used in HS400 device.

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7.1 Power-up

7.1.1 e.MMC Power-up

An e.MMC bus power-up is handled locally in each device and in the bus master. The diagram below illustrates the power-up sequence, which is subsequently described in detail. For comprehensive guidelines, refer to the JEDEC standard JESD84-B51.

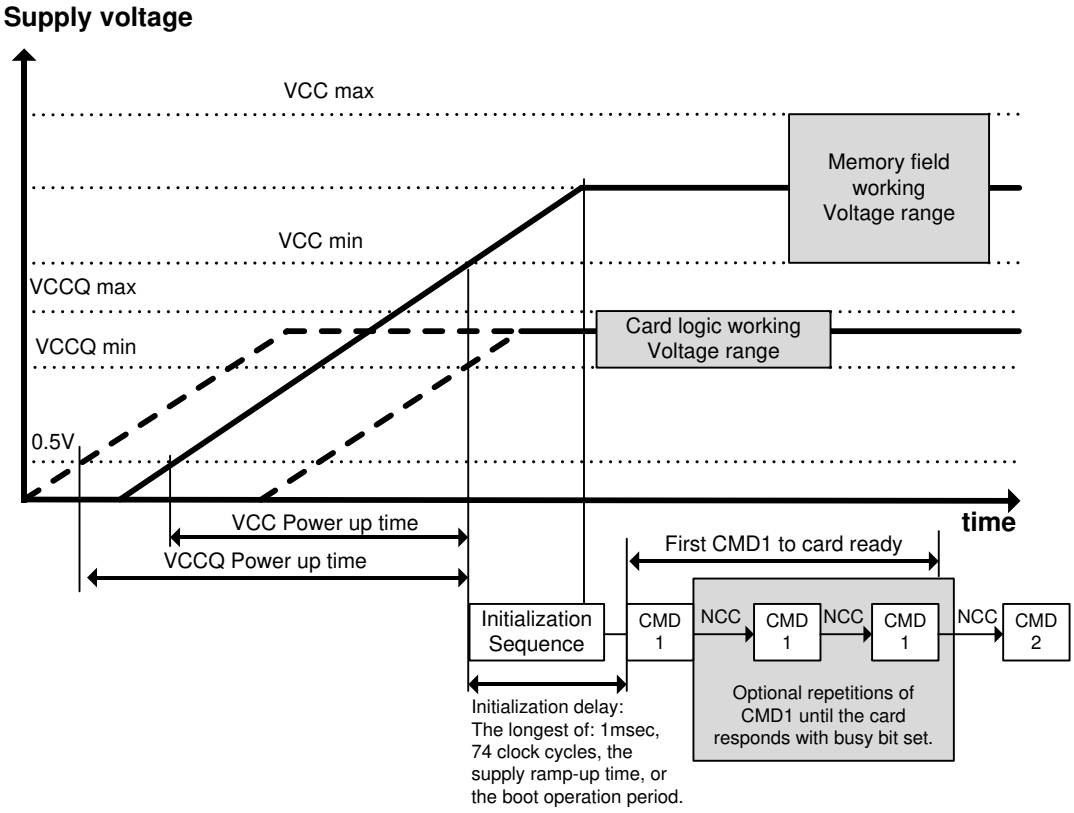


Figure 7-2. Power-up Diagram

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7.1.2 e.MMC Power Cycling

The master can execute any sequence of VCC and VCCQ power-up/power-down. However, the master must not issue any commands until VCC and VCCQ are stable within each operating voltage range. After the slave enters sleep mode, the master can power-down VCC to reduce power consumption. It is necessary for the slave to be ramped up to VCC before the host issues CMD5 (SLEEP_AWAKE) to wake the slave unit. For more information on power cycling, refer to the JEDEC Standard Specification JESD84-B51.

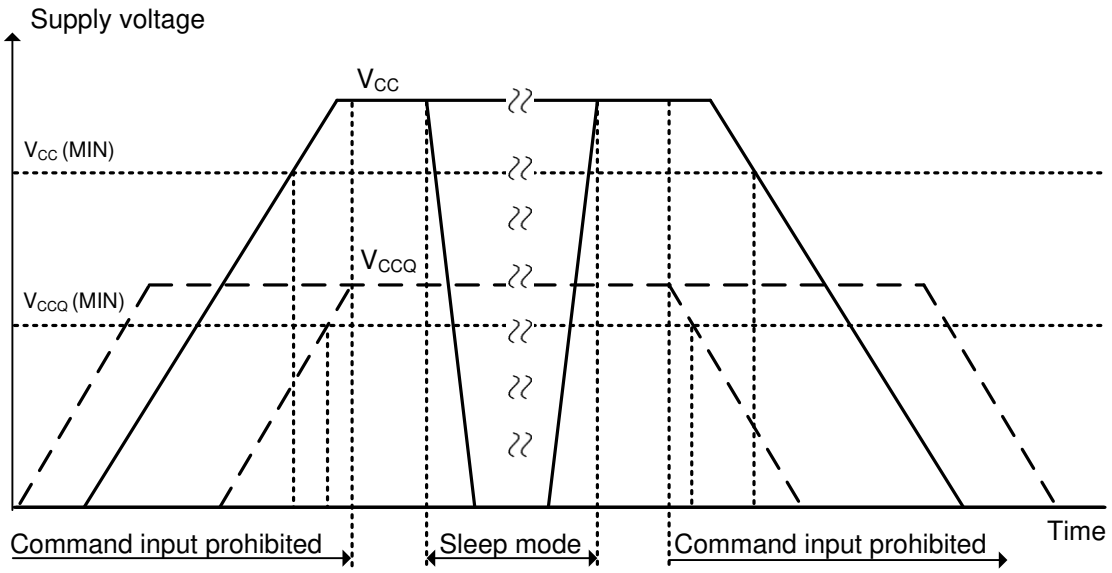


Figure 7-3. e.MMC Power Cycle

7.1.3 Power Cycle Requirement

Ensure VCC/VCCQ power cycle drop below 100mV and supply power after 1ms.

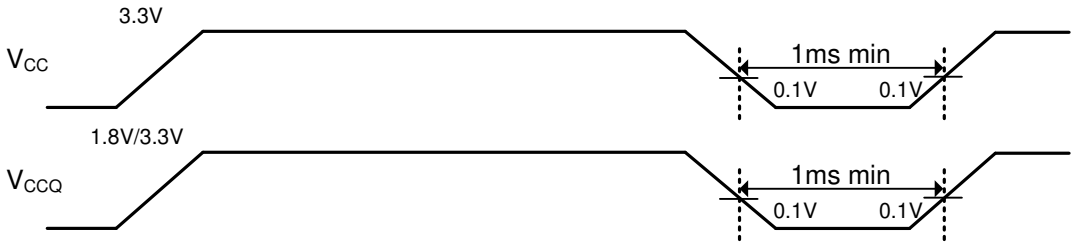


Figure 7-4. Power Cycle Requirement

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7.2 Bus Operating Conditions

Table 7-1. General Operating Conditions

Parameter	Min	Max	Unit
Peak voltage on all lines	-0.5	VCCQ + 0.5	V
All Inputs			
Input Leakage Current (before initialization sequence [1] and/or the internal pull up resistors connected)	-100	100	uA
Input Leakage Current (after initialization sequence and the internal pull up resistors disconnected)	-2	2	uA
All Outputs			
Output Leakage Current (before initialization sequence)	-100	100	uA
Output Leakage Current (after initialization sequence) [2]	-2	2	uA

Note 1. For detailed information on the initialization sequence, refer to the JEDEC standard specification JESD84-B51.
Note 2. DS (Data strobe) pin is excluded.

7.2.1 Power supply

In the e.MMC, VCC is used for the NAND flash device and its interface voltage; VCCQ is for the controller and the MMC interface voltage as shown in the figure below. The core regulator is optional and only required when internal core logic voltage is regulated from VCCQ. A C_{REG} capacitor must be connected to the VDDi terminal to stabilize regulator output on the system.

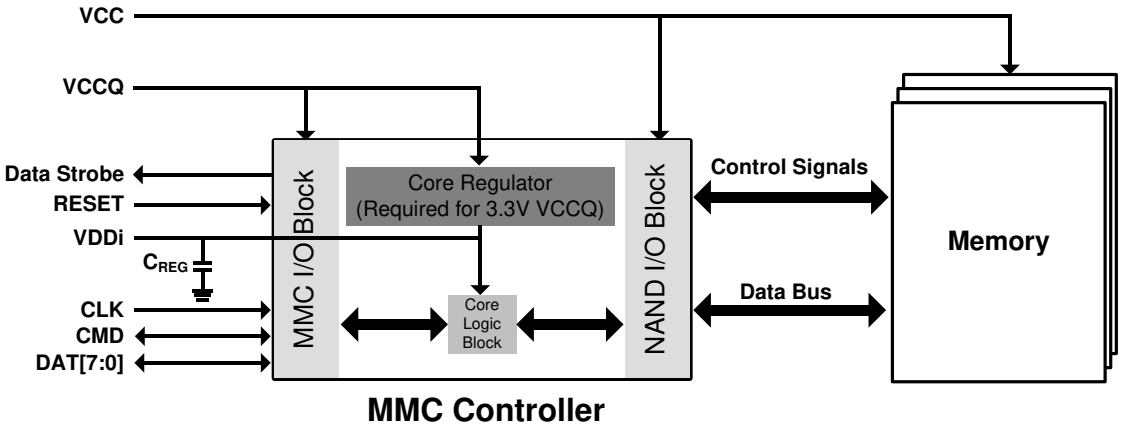


Figure 7-5. e.MMC Internal Power Diagram

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7.2.2 Power supply Voltage

The e.MMC supports one or more combinations of VCC and VCCQ as shown in the table below. The VCCQ must be defined at equal to or less than VCC.

Table 7-2. Operating Voltage

Parameter	Symbol	Min	Max	Unit
Supply voltage (NAND)	VCC	2.7	3.6	V
Supply voltage (I/O)	VCCQ	2.7	3.6	V
		1.7	1.95	V
Supply power-up for 3.3V	tPRUH	0.036	35	ms
Supply power-up for 1.8V	tPRUL	0.018	25	ms

The e.MMC must support at least one of the valid voltage configurations, and can optionally support all valid voltage configurations (see Table).

Table 7-3. Voltage Combinations

Combinations	VCCQ	
	1.7V ~ 1.95V	2.7V ~ 3.6V[1]
VCC = 2.7V ~3.6V	Valid	Valid

Note 1.VCCQ (I/O) 3.3 volt range is not supported in HS200 & HS400 devices.

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7.2.3 Bus Signal Line Load

The total capacitance C_L of each line of the e.MMC bus is the sum of the bus master capacitance C_{HOST}, the bus capacitance C_{BUS} itself and the capacitance C_{DEVICE} of e.MMC connected to this line:

$C_L = C_{HOST} + C_{BUS} + C_{DEVICE}$

The sum of the host and bus capacitances must be under 20pF.

Table 7-4. Signal Line Load

Parameter	Symbol	Min	Typ	Max	Unit	Remark
Pull-up resistance for CMD	R_{CMD}	4.7	10	50	kΩ	to prevent bus floating
Pull-up resistance for DAT0~7	R_{DAT}	10	10	50	kΩ	to prevent bus floating
Internal pull up resistance DAT1~DAT7	R_{RST_n}	4.7	10	50	kΩ	It is not necessary to put pull-up resistance on RST_n (H/W rest) line if host does not use H/W reset. (Extended CSD register [162] = 0b)
Bus signal line capacitance	CL	-	30	30	pF	Single Device
Single Device capacitance	C_{BGA}	-	6	6	pF	
Maximum signal line inductance		-	16	16	nH	
Impedance on CLK / CMD / DAT0~7		45	50	55	Ω	Impedance match
Serial's resistance on CLK line	SR_{CLK}	0	0	47	Ω	
Serial's resistance on CMD / DAT0~7 line	SR_{CMD} $SR_{DAT0\sim7}$	0	0	47	Ω	
VCCQ decoupling capacitor		2.2+0.1	4.7+0.1	4.7+0.22	uF	It should be located as close as possible to the balls defined in order to minimize connection parasitic
	CH1	1	1	2.2	uF	CH1 is for HS200 and HS400. It should be placed adjacent to VCCQ -VSSQ balls (#C6 and #C4 accordingly, next to DAT [7~0] balls). It should be located as close as possible to the balls defined in order to minimize connection parasitic.
VCC capacitor value		2.2+0.1	4.7+0.22	4.7+0.22	uF	It should be located as close as possible to the balls defined in order to minimize connection parasitic.
VDDi capacitor value		1+0.1	2.2+0.1	4.7+0.22	uF	To stabilize regulator output to controller core logics. It should be located as close as possible to the balls defined in order to minimize connection parasitic.

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7.2.4 HS400 reference load

The circuit shown below represents the reference load used to define HS400 device output timing, as well as overshoot and undershoot parameters.

The reference load is made up by the transmission line and the $C_{REFERENCE}$ capacitance.

The reference load is not intended to be a precise representation of the typical system environment nor a depiction of the actual load presented by a production tester.

System designers should use IBIS or other simulation tools to correlate the reference load to system environment. Manufacturers should correlate to their production test conditions.

Delay time (td) of the transmission line has been introduced to make the reference load independent from the PCB technology and trace length.

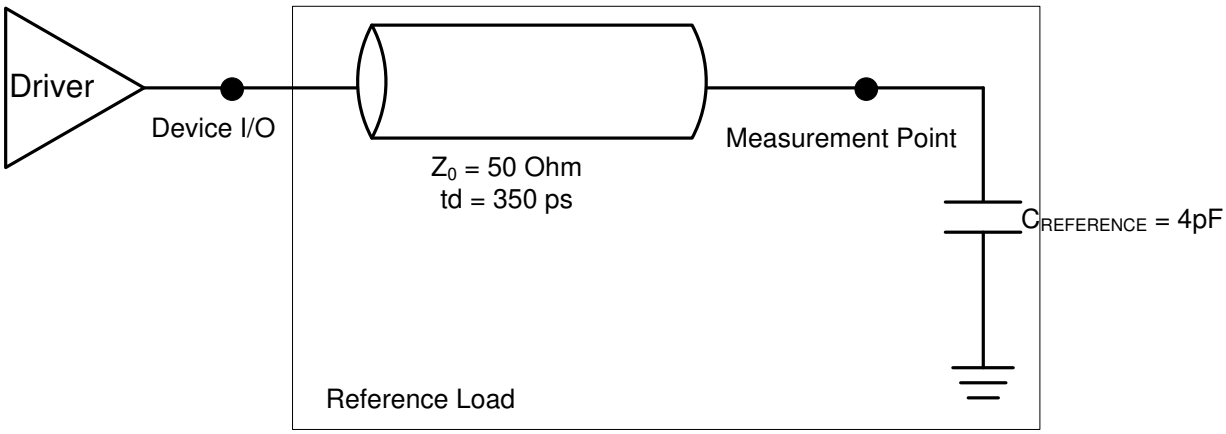


Figure 7-6. HS400 reference load

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7.3 Bus Signal Levels

As the bus can be supplied with a variable supply voltage, all signal levels are related to the supply voltage.

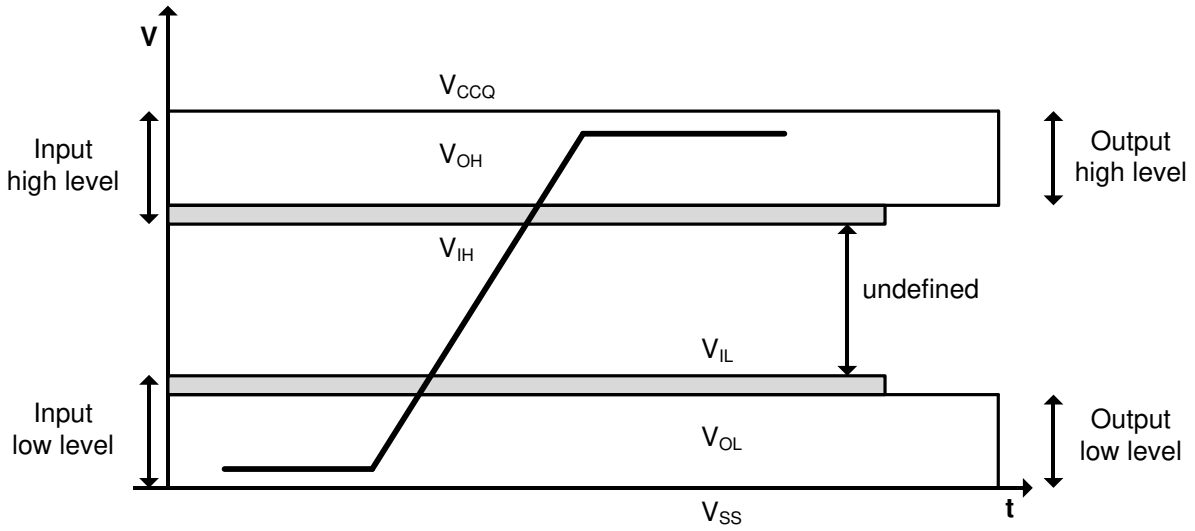


Figure 7-7. Bus Signal Levels

7.3.1 Open-drain Mode Bus Signal Level

Table 7-5. Open-drain Bus Signal Level

Parameter	Symbol	Min	Max	Unit	Conditions
Output HIGH voltage	VOH	VCCQ - 0.2	-	V	IOH = -100 µA
Output LOW voltage	VOL	-	0.3	V	IOL = 2 mA

Note: The input levels are identical with the push-pull mode bus signal levels.

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7.3.2 Push-pull mode bus signal level

The device input and output voltages shall be within the following specified ranges for any VCCQ of the allowed voltage range.

For 2.7V ~ 3.6V VCCQ range (compatible with JESD8C.01)

Table 7-6. Push-pull Signal Level — High-voltage e.MMC

Parameter	Symbol	Min	Max	Unit	Conditions
Output HIGH voltage	VOH	0.75 x VCCQ	-	V	IOH = -100 µA @ VCCQ min
Output LOW voltage	VOL	-	0.125 x VCCQ	V	IOL = 100 µA @ VCCQ min
Input HIGH voltage	VIH	0.625 x VCCQ	VCCQ + 0.3	V	
Input LOW voltage	VIL	VSS - 0.3	0.25 x VCCQ	V	

For 1.7V ~ 1.95V VCCQ range (Compatible with EIA/JEDEC Standard “EIA/JESD8-7 Normal Range” as defined in the following table.)

Table 7-7. Push-pull Signal Level — 1.7V ~ 1.95V VCCQ Voltage Range

Parameter	Symbol	Min	Max	Unit	Conditions
Output HIGH voltage	VOH	VCCQ - 0.45	-	V	IOH = -2 mA
Output LOW voltage	VOL	-	0.45	V	IOL = 2 mA
Input HIGH voltage	VIH	0.65 x VCCQ	VCCQ + 0.3	V	
Input LOW voltage	VIL	VSS - 0.3	0.35 x VCCQ	V	

7.3.3 Bus Operating Conditions for HS200 & HS400

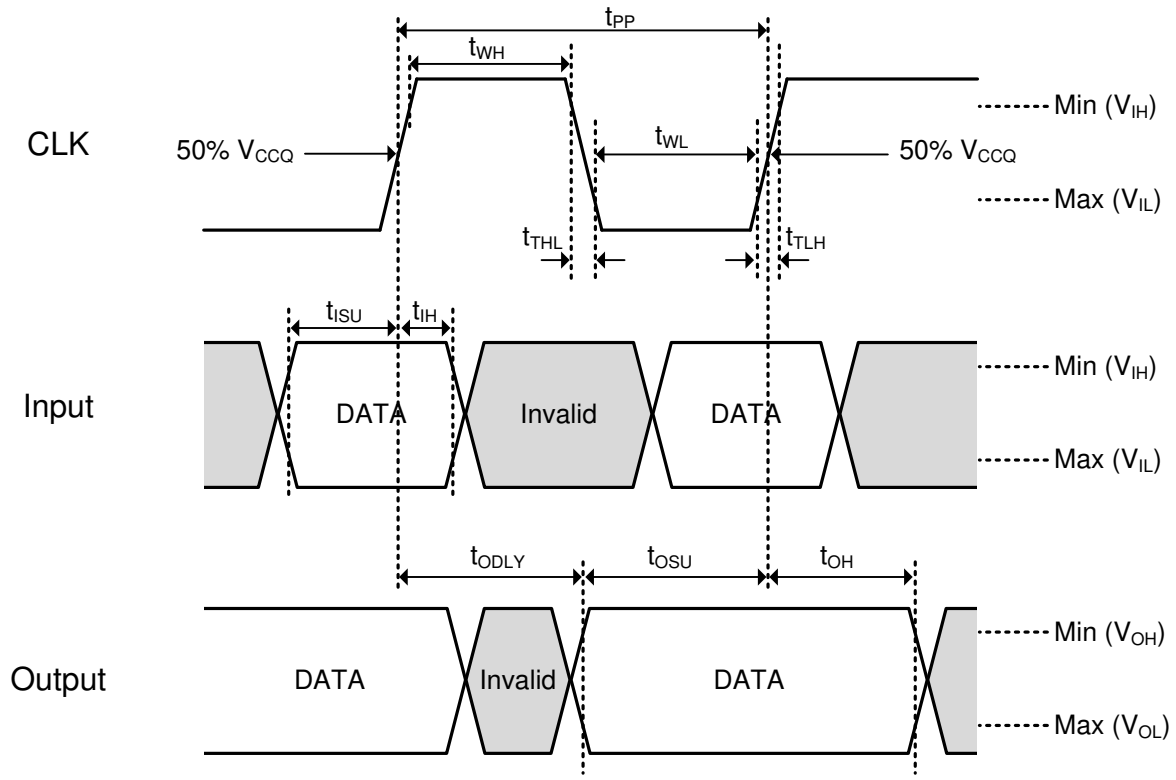
The bus operating conditions for HS200 devices are the same as those specified in JESD84-B51, with the sole exception that VCCQ = 3.3V is not supported.

7.3.4 Device Output Driver Requirements for HS200 & HS400

Refer to the JEDEC Standard Specification JESD84-B51.

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7.4 Bus Timing



Data must always be sampled on the rising edge of the clock.

Figure 7-8. Timing Diagram

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7.4.1 Device Interface Timings

Table 7-8. High-speed Device Interface Timing

Parameter	Symbol	Min	Max	Unit	Conditions
Clock CLK[1]					
Clock frequency Data Transfer Mode (PP)[2]	fPP	0	52[3]	MHz	CL ≤ 30 pF Tolerance:+100KHz
Clock frequency Identification Mode (OD)	fOD	0	400	kHz	Tolerance: +20KHz
Clock high time	tWH	6.5	-	ns	CL ≤ 30 pF
Clock low time	tWL	6.5	-	ns	CL ≤ 30 pF
Clock rise time[4]	tTLH	-	3	ns	CL ≤ 30 pF
Clock fall time	tTHL	-	3	ns	CL ≤ 30 pF
Inputs CMD, DAT (referenced to CLK)					
Input setup time	tISU	3	-	ns	CL ≤ 30 pF
Input hold time	tIH	3	-	ns	CL ≤ 30 pF
Outputs CMD, DAT (referenced to CLK)					
Output delay time during data transfer	tODLY	-	13.7	ns	CL ≤ 30 pF
Output hold time	tOH	2.5	-	ns	CL ≤ 30 pF
Signal rise time[5]	tRISE	-	3	ns	CL ≤ 30 pF
Signal fall time	tFALL	-	3	ns	CL ≤ 30 pF

Note 1. CLK timing is measured at 50% of VDD.

Note 2. e.MMC shall support the full frequency range from 0-26Mhz or 0-52MHz.

Note 3. Device can operate as high-speed Device interface timing at 26 MHz clock frequency.

Note 4. CLK rise and fall times are measured by min (VIH) and max (VIL).

Note 5. Inputs CMD DAT rise and fall times are measured by min (VIH) and max (VIL) and outputs CMD DAT rise and fall times are measured by min (VOH) and max (VOL).

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Table 7-9. Backward-compatible Device Interface Timing

Parameter	Symbol	Min	Max	Unit	Conditions[1]
Clock CLK[2]					
Clock frequency Data Transfer Mode (PP)[3]	fPP	0	26	MHz	CL ≤ 30 pF
Clock frequency Identification Mode (OD)	fOD	0	400	kHz	
Clock high time	tWH	10	-	ns	CL ≤ 30 pF
Clock low time	tWL	10	-	ns	CL ≤ 30 pF
Clock rise time[4]	tTLH	-	10	ns	CL ≤ 30 pF
Clock fall time	tTHL	-	10	ns	CL ≤ 30 pF
Inputs CMD, DAT (referenced to CLK)					
Input setup time	tISU	3	-	ns	CL ≤ 30 pF
Input hold time	tIH	3	-	ns	CL ≤ 30 pF
Outputs CMD, DAT (referenced to CLK)					
Output setup time[5]	tOSU	11.7	-	ns	CL ≤ 30 pF
Output hold time[5]	tOH	8.3	-	ns	CL ≤ 30 pF

Note 1. The Device must always start with the backward-compatible interface timing. The timing mode can be switched to high speed interface timing by the host sending the SWITCH command (CMD6) with the argument for high speed interface select.

Note 2. CLK timing is measured at 50% of VDD.

Note 3. For compatibility with Devices that support the v4.2 standard or earlier, host should not use > 26 MHz before switching to high speed interface timing.

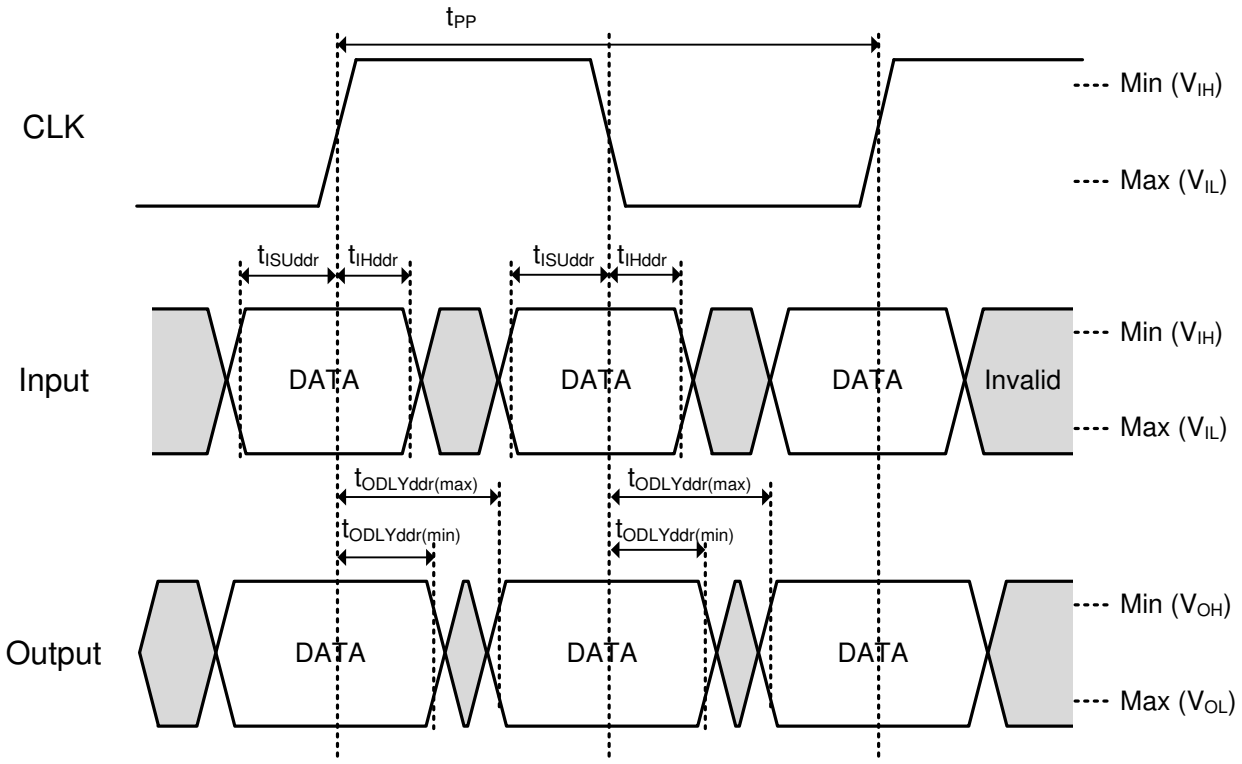
Note 4. CLK rise and fall times are measured by min (VIH) and max (VIL).

Note 5. tOSU and tOH are defined as values from clock rising edge. However, there may be Devices or devices which utilize clock falling edge to output data in backward compatibility mode. Therefore, it is recommended for hosts either to set tWL value as long as possible within the range which will not go over tCK-tOH(min) in the system or to use slow clock frequency, so that host could have data set up margin for those devices. In this case, each device which utilizes clock falling edge might show the correlation either between tWL and tOSU or between tCK and tOSU for the device in its own datasheet as a note or its application notes.

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7.5 Bus Timing for DAT Signals During Dual Data Rate Operation

These timings apply to the DAT[7:0] signals only when the device is configured for dual data mode operation. In this dual data mode, the DAT signals operate synchronously of both the rising and the falling edges of CLK. The CMD signal continues to operate in sync with the rising edge of CLK, in accordance with the specified bus timing, so there is no change in its timing.



In DDR mode data on DAT[7:0] lines are sampled on both edges of the clock (not applicable for CMD line)

Figure 7-9. Data Input/Output in Dual Data Rate Mode

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7.5.1 Dual Data Rate Interface Timing

Table 7-10. High-speed Dual Data Rate Interface Timing

Parameter	Symbol	Min	Max	Unit	Conditions
Clock CLK[1]					
Clock duty cycle		45	55	%	Includes jitter, phase noise
Input DAT (referenced to CLK-DDR mode)					
Input setup time	tISUddr	2.5	-	ns	CL ≤ 20 pF
Input hold time	tIHddr	2.5	-	ns	CL ≤ 20 pF
Output DAT (referenced to CLK-DDR mode)					
Output delay time during data transfer	tODLYddr	1.5	7	ns	CL ≤ 20 pF
Signal rise time (all signals)[2]	tRISE	-	2	ns	CL ≤ 20 pF
Signal fall time (all signals)	tFALL	-	2	ns	CL ≤ 20 pF

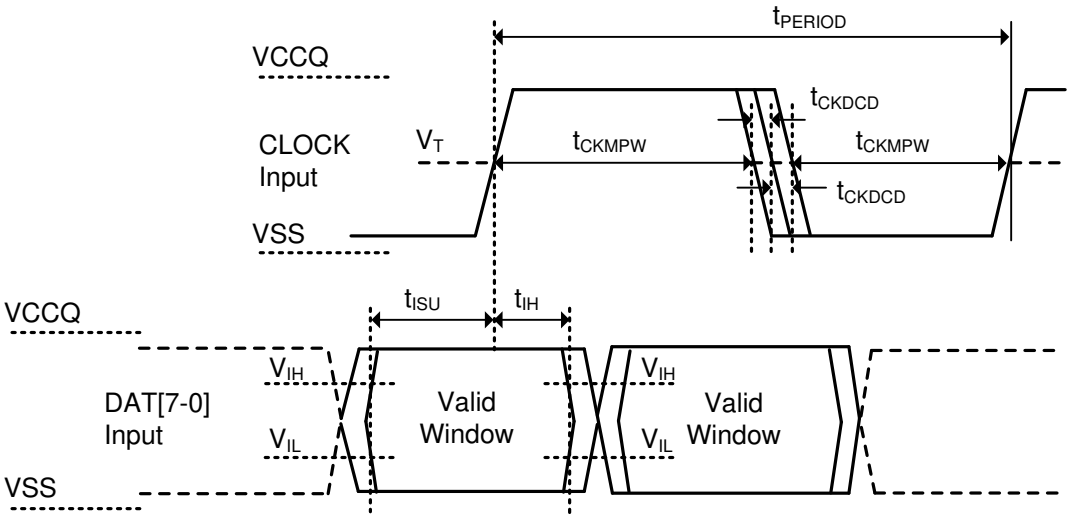
Note 1. CLK timing is measured at 50% of VDD.

Note 2. Inputs CMD, DAT rise and fall times are measured by min (VIH) and max (VIL), and outputs CMD, DAT rise and fall times are measured by min (VOH) and max (VOL)

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7.6 Bus Timing Specification in HS400 mode

7.6.1 HS400 Device Input Timing



Note1: tISU and tIH are measured at VIL (max.) and VIH (min.)
Note2: VIH denotes VIH (min.) and VIL denotes VIL (max.)
Note3: VT = 50% of VCCQ, indicates clock reference point for timing measurements.

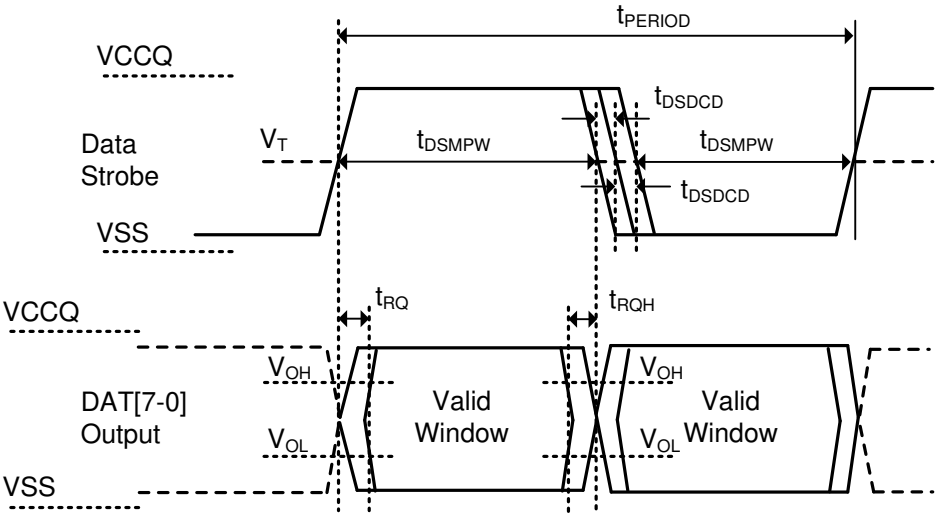
Figure 7-10. HS400 Device Data input timing

Table 7-11. HS400 Device input timing

Parameter	Symbol	Min	Max	Unit	Conditions
Input CLK					
Cycle time data transfer mode	tPERIOD	5	-	ns	200MHz(Max), between rising edges with respect to VT.
Slew rate	SR	1.125	-	V/ns	With respect to VIH/VIL.
Duty cycle distortion	tCKDCD	0.0	0.3	ns	Allowable deviation from an ideal 50% duty cycle. With respect to VT. Includes jitter, phase noise
Minimum pulse width	tCKMPW	2.2	-	ns	With respect to VT.
Input DAT (referenced to CLK)					
Input setup time	tISUddr	0.4	-	ns	CDevice ≤ 6pF With respect to VIH/VIL.
Input hold time	tIHddr	0.4	-	ns	CDevice ≤ 6pF With respect to VIH/VIL.
Slew rate	SR	1.125	-	V/ns	With respect to VIH/VIL.

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7.6.2 HS400 Device Output Timing



Note1: VOH denotes VOH(min.) and VOL denotes VOL(max.)
Note2: VT = 50% of VCCQ, indicates clock reference point for timing measurements.

Figure 7-11. HS400 Device output timing

Table 7-12. HS400 Device output timing

Parameter	Symbol	Min	Max	Unit	Conditions
Data Strobe					
Cycle time data transfer mode	tPERIOD	5	-	ns	200MHz(Max), between rising edges with respect to VT.
Slew rate	SR	1.125	-	V/ns	With respect to VOH/VOL and HS400 reference load
Duty cycle distortion	tDSDCD	0.0	0.2	ns	Allowable deviation from the input CLK duty cycle distortion (tCKDCD) With respect to VT Includes jitter, phase noise
Minimum pulse width	tDSMPW	2.0	-	ns	With respect to VT.
Read pre-amble	tRPRE	0.4	-	tPERIOD	Max value is specified by manufacturer. Value up to infinite is valid
Read post-amble	tRPST	0.4	-	tPERIOD	Max value is specified by manufacturer. Value up to infinite is valid
Output DAT (referenced to Data Strobe)					
Output skew	tRQ	-	0.4	ns	With respect to VOH/VOL and HS400 reference load
Output hold skew	tRQH	-	0.4	ns	
Slew rate	SR	1.125	-	V/ns	

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Table 7-13. HS400 Capacitance and Resistors

Parameter	Symbol	Min	Max	Unit
Pull-up resistance for CMD	RCMD	4.7	50	kΩ
Pull-up resistance for DAT0-7	RDAT	10	50	kΩ
Pull-down resistance for Data Strobe	RDS	10	50	kΩ
Internal pull up resistance DAT1-DAT7	Rint	10	150	kΩ
Single Device capacitance	CDevice	-	6	pF

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8 Package Outline Information

Table 8-1. FBGA (11.5 x 13 x 1.0mm) Dimension Table

Symbol	Dimension in inch			Dimension in mm		
	Min	Nom	Max	Min	Nom	Max
A	--	--	0.039	--	--	1.0
A1	0.007	0.009	0.011	0.17	0.22	0.27
A2	--	0.024	--	--	0.6	--
D	0.449	0.453	0.457	11.40	11.50	11.60
E	0.508	0.512	0.516	12.90	13.00	13.10
D1	--	0.256	--	--	6.50	--
E1	--	0.256	--	--	6.50	--
D2	--	0.098	--	--	2.50	--
E2	--	0.098	--	--	2.50	--
SD	--	0.0098	--	--	0.25	--
SE	--	0.0098	--	--	0.25	--
e	--	0.020	--	--	0.50	--
b	0.010	0.012	0.014	0.25	0.30	0.35

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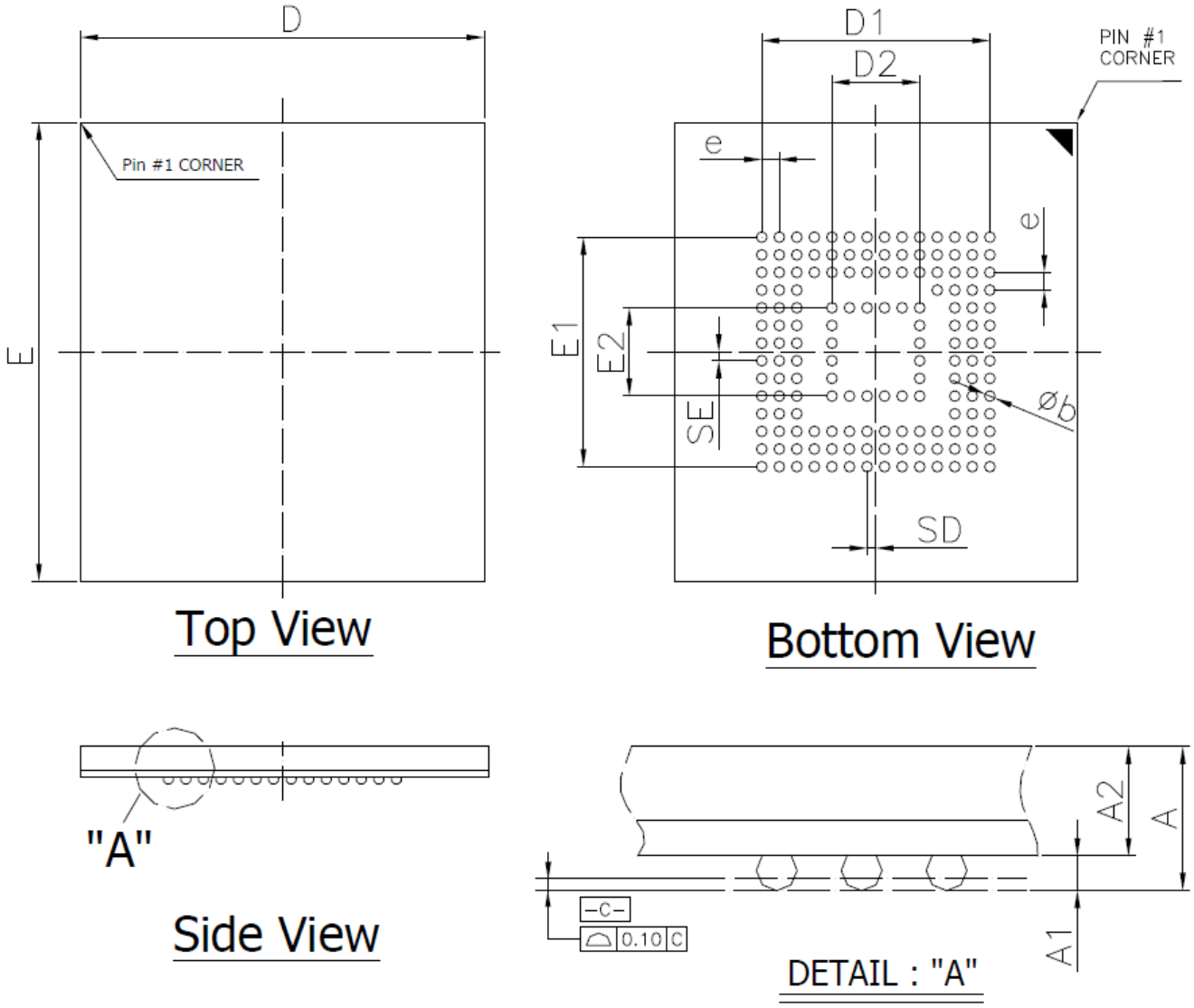


Figure 8-1. Package Outline Drawing Information

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